Large Deflection Electrostatic Spiral Actuator with Twisted-beams

Sachiya Okamoto  Student Member  (University of Hyogo, okamoto.sachiya@elnics.eng.himeji-tech.ac.jp)
Nobuaki Shimamoto  Non-member  (University of Hyogo)
Yuko Matsushita  Non-member  (University of Hyogo)
Takayuki Fujita  Member  (University of Hyogo, fujita@eng.u-hyogo.ac.jp)
Kazusuke Maenaka  Member  (University of Hyogo, maenaka@eng.u-hyogo.ac.jp)
Yoichiro Takayama  Non-member  (University of Hyogo, takayama@eng.u-hyogo.ac.jp)

Keywords : polysilicon surface micromachining, twisted-beam, electrostatic, spiral actuator, large deflection, MEMS

Many electrostatic actuators fabricated by the technology of micro electro mechanical systems (MEMS) have been reported. Especially, the stress-induced or bimetal-like actuators have merits of the simple structure and fabrication steps with relatively large stroke. The stress-induced actuators have a internal tensile-stress layer on a base material, for example a cantilever beam with a Cr layer on Poly-Si layer. The cantilever beam is curved from the substrate by its internal stress.

Conventional stress-induced spiral-actuators are not suitable for increasing a total stroke. In this section, we present a novel spiral actuator whose stroke is a sum of each stroke of constituent beams. We introduce “twisted-beam” as shown in Fig. 1. This beam simultaneously has a curvature to out-of-plane (same as conventional stress-induced actuators) and torsional deflection around longitudinal direction of the beam. The torsional deflection makes the end of curved beams to a horizontal direction, and the next beam connected to that end will start at horizontal plane.

For the convenience of following discussion, we use the word “curved-angle” to represent the angle between the longitudinal median line and the substrate at free end of the beam and “twisted-angle” for the rotational angle between the end face of the beam to the substrate (See Fig. 1(a)). The twisted-beam is formed by many basic cells as shown in Fig. 1(b). The cell of the twisted-beam consists of a relatively wide stress-induced region (base material with stress layer) and a non-stressed region (only base material). In the stress-induced region, three dimensional deflection along a spherical surface occurs, whereas there is no deflection in the non-stress region. The connection between the stress-induced region and the non-stressed region is off-centered and the non-stressed region is inclined to the stress-induced region. Thus the cell has not only a curved-angle but twisted-angle. The curved-angle mainly depends on the length of the stress layer, and the twisted-angle depends on the width of the stress layer and the offset of the connection. The appropriate design is required for the optimized cell structure where the twisted-angle compensates the curved-angle so that next beam starts at horizontal plane. The dimensions of Fig. 1 were determined so that the twisted-angle becomes equal with the curved-angle for the compensation of the effect of the curvature to the out-of-plane.

Figure 2 shows SEM photographs of the spiral actuators with twisted-beams (a) and conventional stress-induced beams (b). Clearly, large deflection can be seen in the actuator with twisted-beams. On the contrary, the actuator with conventional beams not only has small deflection but also becomes entangled. The detailed discussion is omitted here, but this phenomenon, the torsional deviation in x-y plane, can be theoretically calculated for the actuators with relatively large stress in the stress-induced region. Maximum displacement to z-axis is about 750 µm whereas the displacement or shift in x-y plane is around 100-300 µm. This characteristic must be taken into account for the system design including a load of the actuators.
Large Deflection Electrostatic Spiral Actuator with Twisted-beams

Sachiya Okamoto* Student Member
Nobuaki Shimamoto* Non-member
Yuko Matsushita* Non-member
Takayuki Fujita* Member
Kazusuke Maenaka* Member
Yoichiro Takayama* Non-member

In this paper, we propose a large-deflection electrostatic spiral-actuator with novel twisted-beams fabricated by surface micromachining. The stress-induced or bimetal-like actuators have merits of simple structure and fabrication steps with relatively large stroke. The novel stress-induced actuator presented here is composed of 'twisted-beams', which have not only out-of-plane curvature but also rotation along its longitudinal direction. When the twisted-beams are used as components of a spiral actuator, the total stroke of the actuator becomes a sum of each deflection of the beams, and the stroke is much larger than conventional stress-induced spiral actuators. The experimental results of the spiral actuator show the maximum deflection of about 750 µm, which is extremely large for stress-induced-actuators.

Keywords: polysilicon surface micromachining, twisted-beam, electrostatic, spiral actuator, large deflection, MEMS

1. Introduction

Many electrostatic actuators fabricated by the technology of micro electro mechanical systems (MEMS) have been reported. Especially, the stress-induced or bimetal-like actuators have merits of the simple structure and fabrication steps with relatively large stroke. The stress-induced actuators have a internal tensile-stress layer on a base material, for example a cantilever beam with a Cr layer on Poly-Si layer. The cantilever beam is curved from the substrate by its the internal stress. The cantilever can be attracted to the substrate by electrostatic force when the voltage is applied to the beam and the substrate through the insulating layer on the substrate. Many types of actuators using this mechanism have been reported(1)-(4), which include RF-switches(5)(6), micro valves(7), micro turbines(8), optical switches(9), etc. Some of these devices are already in the market. For increasing area factor and decreasing operation voltage, the actuators with spiral or conical shape have also been reported(10)(11). In such devices, operation voltage and area factor can be reduced, however they cannot increase the actuation stroke because the stroke of the beam is defined only by the distance between the free end and fixed point of the spiral but not by total length of the beam in the spiral. Thus, for increasing total stroke, the novel concept has to be introduced.

In this report, we propose the “twisted-beam” which has both curvatures to out-of-plane and rotation along longitudinal direction of the beam, and examine the spiral actuators constructed with the twisted-beams.

2. Operation of Conventional Stress-induced Cantilevers

Fig. 1 shows the structure of a conventional stress-induced cantilever beam, which has a Au/Cr layer for a tensile-stress layer on Poly-Si as a base material. Because the base material is uniformly covered with the stress layer, the curvature of the film is constant over the whole surface. Therefore, the beam lies on the circular arc depending on the film thickness, Young’s modulus and internal stress. The radius of curvature \( R \) of the stress-induced surface is given by(9),

\[
R = \frac{E_s h [3m + K (n(1 + n)^{-1})]}{6 (m \sigma - \sigma)} \tag{1}
\]

\[
K = 1 + 4mn + 6mn^2 + 4mn^3 + m^2 n^2 \tag{2}
\]

where \( E \) is the Young's modulus, \( h \) is the thickness, \( \sigma \) is the residual stresses. The subscripts 1 and 2 indicate the values for Au/Cr and Poly-Si, respectively. The out-of-plane displacement at the free end of the beam \( z \) is described by

\[
z = R(1 - \cos \left( \frac{L}{R} \right)) \tag{3}
\]

where \( L \) is the length of the cantilever beam. This result implies that the maximum displacement of the spiral structure is defined only by the radius of the spiral and is the same as the straight cantilever with the equal length to the radius of the spiral structure. In the following, the above discussion will be verified using FEM analysis.

Fig. 2 shows the result of the FEM analysis for a spiral actuator, which has three straight-beams connected in series at right angle. The beam 1, whose one end is fixed to the substrate, is curved with the radius described by eq. (1). The free end of the beam 1 has an angle from the substrate, \( \theta \), due to the curvature of the beam. Thus, the beam 2, which is perpendicularly connected to the...
Large Deflection Electrostatic Spiral Actuator with Twisted-beams

end of the beam 1, has an initial inclined angle at its starting point. Accordingly, the beam 3 will start to curve with an angle toward the substrate (see * point in Fig. 2). Thus, the z-position at the free end of the beam 3 is lowered from its starting point in this dimension and total stroke does not equal to a sum of each deflection of the beams.

3. Twisted-Beams

3.1 Concept As described above, conventional stress-induced spiral actuators are not suitable for increasing a total stroke. In this section, we present a novel spiral actuator whose stroke is a sum of each stroke of constituent beams. We introduce “twisted-beam” as shown in Fig. 3. The twisted-beam is formed by some of cells which contain a stress-induced region and non-stressed region. The stressed-induced region and non-stressed region are connected together by off-centered link as shown in Figs. 3 and 4. In the stress-induced region, the beam curves along a spherical surface. The longitudinal curvature makes a vertical displacement of the beam. On the other hand, the transversal curvature in the stress-induced region gives a torsional displacement of the beam because the next cells are connected by off-centered link. Thus the beam simultaneously has a curvature to out-of-plane (same as conventional stress-induced actuators) and torsional deflection around longitudinal direction of the beam. The torsional deflection makes the end of curved beams to a horizontal direction, and the next beam connected to that end will start at horizontal plane. In other words, the end of the beam 2 marked with * in Fig. 2 is rotated clockwise when the beam 2 is twisted-beam. Thus, by using twisted-beams, total stroke of the spiral actuator becomes to be a sum of each deflection of the beams.

3.2 Basic Design For optimization of the device, the relation between a curvature to out-of-plane and torsional deflection is important. For the convenience of following discussion, we use the word “curved-angle” to represent the angle between the longitudinal median line and the substrate at free end of the beam and “twisted-angle” for the rotational angle between the end face of the beam to the substrate (See Fig. 3(a)). The twisted-beam is formed by many basic cells as shown in Fig. 3(b). The cell of the twisted-beam consists of a relatively wide stress-induced region (base material with stress layer) and a non-stressed region (only base material). In the stress-induced region, three dimensional deflection along a spherical surface occurs according to eq. (1)~(3), whereas there is no deflection in the non-stress region. The connection between the stress-induced region and the non-stressed region is off-centered and the non-stressed region is inclined to the stress-induced region. Thus the cell has not only a curved-angle but twisted-angle. The curved-angle mainly depends on the length of the stress layer, and the twisted-angle depends on the width of the stress layer and the offset of the connection. The appropriate design is required for the optimized cell structure where the twisted-angle compensates the curved-angle so that next beam starts at horizontal plane. The dimensions of Fig. 3 were determined so that the twisted-angle becomes equal with the curved-angle for the compensation of the effect of the curvature to the out-of-plane. Fig. 4 shows the results of FEM analysis of the twisted-beam. The influence of the gravity to deflection of the beam can be neglected (less than 1% of total deflection) because the weight of the beam is sufficiently small against stiffness of the beam. Fig. 5 shows the twisted-angle and curved-angle for the number of connected cells, where the angles are almost equal regardless of the number of the cells.

The curved-angle directly determines the stroke or maximum deflection of the actuator. In our device, the stress-induced region is a part of the beam and the stroke may be lower than the one for conventional devices in which the stress-induced region covers whole surface of the beam. Fig. 6 indicates the maximum deflections of our device and conventional device as a function of the beam length. The stroke of our device is about 3/5 of conventional one.

3.3 Spiral Actuator Fig. 7 shows an example of the
designed spiral actuator with twisted-beams. A $2^{1/4}$-turn spiral is
anchored to the insulating layer on the substrate at its center. The
first or anchored straight-beam is not a twisted-beam but
conventional beam. The device size is $850 \times 850 \, \mu m^2$. Total of 44
cells are used. Fig. 8 shows the results of FEM analysis on the
assumption of the internal stress of 200 MPa which is calculated
from a combination of Au/Cr on Poly-Si films for the
stress-induced layer. From horizontal view in Fig. 8, it is clear that
the total stroke is a sum of each stroke of the twisted-beams. Maximum displacement or stroke was calculated to be about 930 µm which is extremely large value in micro actuators. As for generation force, the pull up force or restoring force of the spiral spring is calculated to be 29.4 nN, whereas the pull down force to the substrate is depend on the applied voltage.

3.4 Mechanical Strength Against Acceleration or Shock

Our actuator has an irregular shape in the beams, which is a combination of zigzag pattern. It may bring about stress concentration, and the mechanical strength of the beam should be estimated. Here, we applied the static acceleration to the device, and maximum stress and deviation of the structure were calculated by FEM analysis. As a load of the actuators, the mass with size of 800×800 µm² in a Poly-Si layer was appended to the top of the actuator in the calculation. This simulates an optical mirror driven by the top of this actuator. Fig. 9 shows the deviation and stress distribution when 1G acceleration is applied to the z-axis. The deviation at free end of the actuator is ~6µm, and maximum stress of 74MPa appears near the anchor point. In Fig. 10, the deviation and stress distribution for 1G acceleration applied to x and y axes are shown. Maximum deviation and stress are less than 10nm and 74kPa, respectively. Since the failure strength of the Poly-Si is around 2000-2700 MPa, and our actuator can be proof against an acceleration or shock of several tens of G.

4. Fabrication Process

The fabrication process is based on the two-layer polysilicon surface-micromachining process. A schematic view of the process flow is shown in Fig. 11. At first, (a) a silicon wafer is prepared. (b) A 0.36µm thermal oxide is grown on the Si substrate followed by a 0.5µm LPCVD silicon nitride layer as an electrical isolation layer. The deposition temperature and growth pressure of silicon nitride are 830 ℃ and the deposition conditions are the temperature of 650 ℃ and the pressure of 0.5Torr. The source gases are mixture of ammonia (100%) and mono-silane (N₂ Base 20.0%) with the ratio of 3:1. The deposition rate was about 3nm/min. (c) Then, a 0.5µm LPCVD polysilicon layer (Poly0) is deposited. The deposition conditions are the temperature of 650 ℃ and the pressure of 0.5Torr. The source gas is mono-silane (N₂ Base 20.0%). The deposition rate was about 8nm/min. The wafer is then lithographically patterned with the mask of Poly0 and etched by the polysilicon wet etchant. The polysilicon etchant is the mixture of HNO₃: HF : H₂O (25 : 1 : 25) (12). This solution has high selectivity to a photoresist and a nitride layer. (d) Next, the SOG is coated for planarization. After planarization, the wafer is annealed at 1100 ℃ for 90min in N₂. Phosphorus is doped into Poly0 from SOG by this anneal. On the planarized surface, 2.0µm sputtered oxide is deposited by RF magnetron sputter. In order to improve the uniformity of the oxide thickness, the wafer is rotated during the sputtering. On the sputtered oxide, SOG is coated again and annealed for doping Poly1 with phosphorus. (e) The wafer is then patterned with the mask of dimples and etched by RIE. The depth of dimples is 0.75µm. The roles of the dimples are (1) prevention of sticking between the beam and substrate, and (2) reinforcement of the non-stressed region by a kind of rib structure. After dimple etch, a next mask for anchor is applied and etched by RIE. (f) Then, the structural layer of polysilicon (Poly1) is deposited with a thickness of 2µm by LPCVD. (g) Again, the SOG is coated over the Poly1 and the wafer is annealed at 1100 ℃ for 90min. This anneal is not only for doping the phosphorus from the top and bottom but also for reducing internal stress of Poly1. (h) The Poly1 is patterned and etched using the SOG as a hard mask of the RIE. After the etching of Poly1 is completed, the SOG hard mask is removed using BHF. (i) Then, the bonding pads and the stresslayer are patterned and gold with a thin chromium layer is sputtered. On the sputtered oxide, SOG is coated again and freeze-dried. Fig. 12 shows the photograph of the fabricated twisted-beams.

5. Experiments

At first, we estimated the internal stress of the Au/Cr layer by measuring the curvature of the test wafer with the Au/Cr layer (13). The stress was estimated to be around 200 MPa which is consistent with the designed value as described in Section 3. As clearly shown in Fig. 12, the test device of the twisted-beam shows both curved-angle and twisted-angle. By measuring microscope, we examined the curved- and twisted-angles for...
straight beams with a number of cells as a parameter. The measured values are shown in Fig. 13 with FEM analysis results. The measured maximum deflection or curved-angle agrees well with the analysis, but there are some differences for the twisted-angles. This difference may be due to miss alignment of the dimple pattern. In the design, the dimple is arranged at center of the non-stressed region to reinforce it. However, in the actual device, the dimple pattern was shifted towered the stress-induced region (cf. Fig. 12(a)) resulting in the reduced curvature of the stress-induced region at the off-centered link. Thus the measured twisted-angle becomes smaller than the results from FEM analysis.

Fig. 14 shows SEM photographs of the spiral actuators with twisted-beams (a) and conventional stress-induced beams (b). Clearly, large deflection can be seen in the actuator with twisted-beams. On the contrary, the actuator with conventional beams not only has small deflection but also becomes entangled. The detailed discussion is omitted here, but this phenomenon, the torsional deviation in x-y plane, can be theoretically explained for the actuators with relatively large stress in the stress-induced region. Table 1 shows the measured displacement of the corners (points (a)-(i) in Fig. 15) of the spiral. Maximum displacement to z-axis of 750 µm was obtained, whereas the analytical value was 930 µm. This difference is results from individual effect of the miss-alignment of the dimple patterns for each beam. The displacement or shift in x-y plane was also observed, however this shift is much smaller than the conventional one (Fig. 14). This characteristic must be taken into account for the system design including a load of the actuators.

The operation of the actuator was confirmed by applying DC voltage between the spiral and the substrate as shown in Fig. 16. The voltage of 200V generates enough force to pull down whole spiral structure to the substrate. The photographs in Fig. 17 show the perspective views of the structure with and without driving voltage. Complete stroke was obtained with maximum response time of around 0.5 s.

Table 1. Displacement at each position of the spiral actuator

<table>
<thead>
<tr>
<th>X-axis[µm]</th>
<th>Y-axis[µm]</th>
<th>Z-axis[µm]</th>
</tr>
</thead>
<tbody>
<tr>
<td>(a) 0</td>
<td>2</td>
<td>16.4</td>
</tr>
<tr>
<td>(b) 13</td>
<td>13</td>
<td>74.6</td>
</tr>
<tr>
<td>(c) 39</td>
<td>-1</td>
<td>140</td>
</tr>
<tr>
<td>(d) 29</td>
<td>-65</td>
<td>213</td>
</tr>
<tr>
<td>(e) -54</td>
<td>-58</td>
<td>253</td>
</tr>
<tr>
<td>(f) -16</td>
<td>104</td>
<td>411</td>
</tr>
<tr>
<td>(g) 156</td>
<td>61</td>
<td>481</td>
</tr>
<tr>
<td>(h) -93</td>
<td>-187</td>
<td>612</td>
</tr>
<tr>
<td>(i) -263</td>
<td>-108</td>
<td>749</td>
</tr>
</tbody>
</table>
Large Deflection Electrostatic Spiral Actuator with Twisted-beams

6. Conclusions
The novel electrostatic stress-induced actuator with large stroke was described. The actuator is composed of “twisted-beams” which have out-of-plane curvature and rotation along its longitudinal direction. By using twisted-beams for spiral actuator, the total stroke becomes a sum of each deflection of the beams, contrary to conventional stress-induced actuators. The example of 800 × 800 μm² shows maximum stroke of 750 μm, which is extremely large stroke in stress-induced actuators. This actuator is useful for an large deflection optical mirror or anywhere the large deflection is required. In current stage, generation force is somewhat small, however, it can be improved by redesigning the cell of twisted-beam (e.g. larger cell) for individual applications.

(Manuscript received Aug. 29, 2005, revised Feb. 3, 2006)

References